



### **QUAD TVS/ZENER ARRAY FOR ESD PROTECTION**

This Quad TVS/Zener Array family have been designed to protect sensitive equipment against ESD in CMOS circuitry operating at 5V. This TVS array offers an integrated solution to protect up to 4 data lines in applications, where the board space is a premium, in a Quad Flat no-Lead package that only occupies an area of 1.8 sq mm.

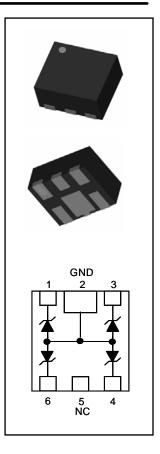
#### SPECIFICATION FEATURES

- IEC61000-4-2 ESD 20kV air, 15kV Contact Compliance
- Low Leakage Current, Maximum of 1µA at rated voltage
- Maximum Capacitance of 35pF per device at 0Vdc 1MHz
- Peak Power Dissipation of 40W under 8/20µs Waveform
- Quad Flat No Lead package QFN (1.2x1.5 sq mm, Height: 0.75mm)
- Lead Free Package 100% Tin Plating, Matte finish

#### **APPLICATIONS**

- Personal Digital Assistant (PDA)
- Digital Cameras
- Portable Instrumentation
- Mobile Phones and Accessories
- MP3 Players





### **MAXIMUM RATINGS (Per Device)**

Rating	Symbol	Value	Units
Peak Pulse Power (8/20µs Waveform)	P <sub>PP</sub>	40	W
Peak Pulse Current (8/20µs Waveform)	I <sub>PPM</sub>	4.5	А
ESD Voltage (HBM Per MIL STD883C - Method 3015-6)	V <sub>ESD</sub>	25	kV
Operating Temperature Range	TJ	-55 to +150	°C
Storage Temperature Range	T <sub>stg</sub>	-55 to +150	°C

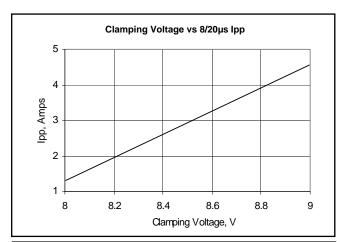
## ELECTRICAL CHARACTERISTICS (Per Device) Tj = 25°C

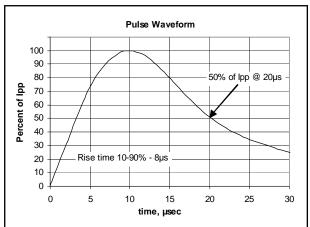
Parameter	Symbol	Conditions	Min	Typical	Max	Units
Reverse Stand-Off Voltage	V <sub>WRM</sub>				5	V
Reverse Breakdown Voltage	$V_{BR}$	I <sub>BR</sub> =1mA	6			V
Reverse Leakage Current	I <sub>R</sub>	V <sub>R</sub> =5V			1	μΑ
Clamping Voltage (8/20µs)	V <sub>c</sub>	Ipp =4A		8.81	9	V
Off State Junction Capacitance	Cj	0 Vdc Bias f = 1MHz betweeen I/O lines and		30	35	pF

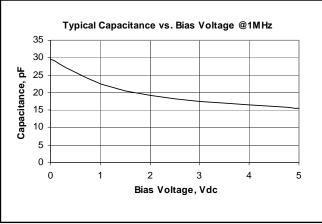




# TYPICAL CHARACTERISTIC CURVES (Per Device) Tj = 25°C



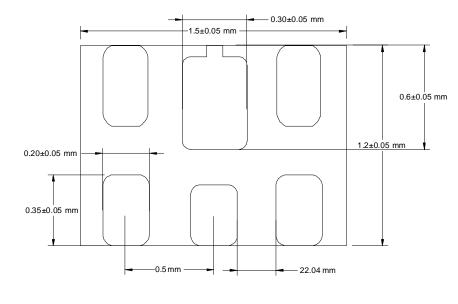


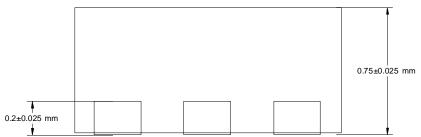


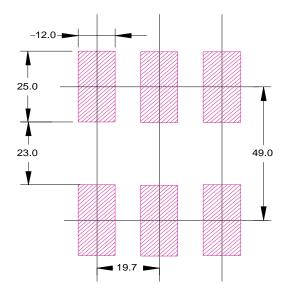




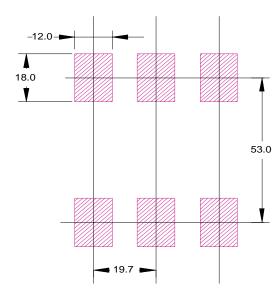
# PACKAGE DIMENSIONS AND SUGGESTED PAD LAYOUT







Suggested Pad Layout (in mils)



Alternate Pad Layout SOT666 (in mils)